# **HIGH ENERGY DEVICES**

# UBD/UBT/UGT Series Uni-Imps



#### **Features**

- Fast impulse breakdown (≤ 120% of typical DC breakdown to 200kV/µs)
- Tight DC breakdown voltage tolerance (±10%)
- Non-radioactive
- Low capacitance

#### **Applications**

- Antenna feedlines
- Test equipment
- Video displays
- Medical electronics
- Instrumentation circuits

#### **Standard Voltages**

Series	DC Breakdown Voltage (Nom)	Unit
UBD	550	V
	600	V
	650	V
	750	V
	850	V
	1.0	kV
	1.2	kV
	1.5	kV
	2.0	kV
	2.5	kV
	3.0	kV
	4.0	kV
UBT	4.0	kV
and	5.0	kV
UGT	6.0	kV
	7.5	kV
	10.0	kV
	12.0	kV
	15.0	kV
	20.0	kV

Devices in the UBD/UBT/UGT Series with other breakdown voltages in the .55-20kV range are available upon request.

#### Description

High Energy Devices' Uni-Imps high-speed transient surge protectors (0.55-20kV) provide the ultimate protection from high-energy, fast-rising transients such as Nuclear EMP. These devices are constructed using a proprietary semiconductor junction process that results in nanosecond response times combined with peak current ratings in the 5-10kA range. A unique benefit of this technology is that the breakdown voltage is virtually independent of the rise time of the transient. In addition, the low capacitance of these devices allows for direct placement on high-frequency lines and antenna feeds without excessive loading.

#### **Ordering Information**

A complete part number is represented by the digits below. Breakdown voltages are expressed in Volts for devices <1000V and kV for devices  $\geq$  1kV. For example, UBD550 is a 550V UBD series device, UBT7.5 is a 7.5kV UBT series device and UGT10.0 is a 10kV UGT series device.

Product Series / Part Number	Breakdown Voltage
UBDXXX	550-950V
UBDX.X	1.0-4.0kV
UBTX.X	4.0-9.0kV
UBTXX.X	10.0-20.0kV
UGTX.X	4.0-9.0kV
UGTXX.X	10.0-20.0kV

All Uni-Imps are available with .360 O.D. endcaps. UBDs are available with a threaded male termination (#8-32) on one end while UGTs are also available with .250 O.D. endcaps.

#### Specifications (@25°C)

			UBD550			UBD600			UBD650				
Parameter	Conditions	Symbol	Min	Nom	Max	Min	Nom	Max	Min	Nom	Max	Units	
Device Specifications													
DC Breakdown	100V/s	V <sub>BD</sub>	495	550	605	540	600	660	585	650	715	V	
Impulse Breakdown	5kV/µs	V <sub>bd</sub>	-	-	660	-	-	720	-	-	780	V	
Insulation Resistance	100V	IR	-	10 <sup>10</sup>	-	-	10 <sup>10</sup>	-	-	10 <sup>10</sup>	-	Ω	
Capacitance	1MHz	С	-	-	20.0	-	-	20.0	-	-	20.0	рF	
Life Ratings	Life Ratings												
Surge Life	3kA (PW=15µs)	-	330	-	-	420	-	-	500	-	-	surges	

#### Specifications (@25°C)

				UBD750		UBD850			UBD1.0			
Parameter	Conditions	Symbol	Min	Nom	Max	Min	Nom	Max	Min	Nom	Max	Units
Device Specifications												
DC Breakdown	100V/s	V <sub>BD</sub>	675	750	825	765	850	935	900	1000	1100	V
Impulse Breakdown	5kV/µs	V <sub>bd</sub>	-	-	900	-	-	1020	-	-	1200	V
Insulation Resistance	100V	IR	-	10 <sup>10</sup>	-	-	10 <sup>10</sup>	-	-	10 <sup>10</sup>	-	Ω
Capacitance	1MHz	С	-	-	20.0	-	-	20.0	-	-	15.0	рF
Life Ratings												
Surge Life	3kA (PW=15µs)	-	660	-	-	830	-	-	1,080	-	-	surges

# Specifications (@25°C)

			UBD1.2				UBD1.5	;		UBD2.0	)	
Parameter	Conditions	Symbol	Min	Nom	Max	Min	Nom	Max	Min	Nom	Max	Units
Device Specifications												
DC Breakdown	100V/s	V <sub>BD</sub>	1.08	1.20	1.32	1.35	1.50	1.65	1.80	2.00	2.20	kV
Impulse Breakdown	5kV/µs	V <sub>bd</sub>	-	-	1.44	-	-	1.80	-	-	2.40	kV
Insulation Resistance	100V	IR	-	10 <sup>10</sup>	-	-	10 <sup>10</sup>	-	-	10 <sup>10</sup>	-	Ω
Capacitance	1MHz	С	-	-	15.0	-	-	15.0	-	-	10.0	рF
Life Ratings												
Surge Life	3kA (PW=15µs)	-	1,410	-	-	1,900	-	-	2,400	-	-	surges

## Specifications (@25°C)

			UBD2.5				UBD3.0			)			
Parameter	Conditions	Symbol	Min	Nom	Max	Min	Nom	Max	Min	Nom	Max	Units	
Device Specifications													
DC Breakdown	100V/s	V <sub>BD</sub>	2.25	2.50	2.75	2.70	3.00	3.30	3.60	4.00	4.40	kV	
Impulse Breakdown	5kV/µs	V <sub>bd</sub>	-	-	3.00	-	-	3.60	-	-	4.80	kV	
Insulation Resistance	100V	IR	-	10 <sup>10</sup>	-	-	10 <sup>10</sup>	-	-	10 <sup>10</sup>	-	Ω	
Capacitance	1MHz	С	-	-	10.0	-	-	5.0	-	-	5.0	рF	
Life Ratings	Life Ratings												
Surge Life	3kA (PW=15µs)	-	2,400	-	-	2,400	-	-	2,400	-	-	surges	

# **HIGH ENERGY DEVICES**

## Specifications (@25°C)

				UBT4.0 UBT5.0 UGT4.0 UGT5.0								
Parameter	Conditions	Symbol	Min	Nom	Max	Min	Nom	Max	Min	Nom	Max	Units
Device Specifications												
DC Breakdown	100V/s	V <sub>BD</sub>	3.60	4.00	4.40	4.50	5.00	5.50	5.40	6.00	6.60	kV
Impulse Breakdown	5kV/µs	$V_{bd}$	-	-	4.80	-	-	6.00	-	-	7.20	kV
Insulation Resistance	100V	IR	-	10 <sup>10</sup>	-	-	10 <sup>10</sup>	-	-	10 <sup>10</sup>	-	Ω
Capacitance	1MHz	С	-	-	5.0	-	-	3.0	-	-	3.0	рF
Life Ratings												_
Surge Life	10kA (PW=15µs)	-	1,300	-	-	1,300	-	-	1,300	-	-	surges

## Specifications (@25°C)

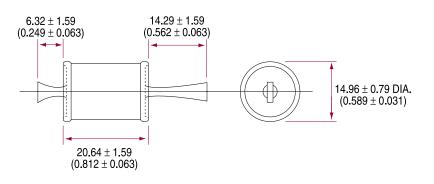
			UBT7.5 UGT7.5			UBT10.0 UGT10.0			UBT12.0 UGT12.0			
Parameter	Conditions	Symbol	Min	Nom	Max	Min	Nom	Max	Min	Nom	Max	Units
Device Specifications												
DC Breakdown	100V/s	V <sub>BD</sub>	6.75	7.50	8.25	9.00	10.00	11.00	10.80	12.00	13.20	kV
Impulse Breakdown	5kV/µs	V <sub>bd</sub>	-	-	9.00	-	-	12.00	-	-	14.40	kV
Insulation Resistance	100V	IR	-	10 <sup>10</sup>	-	-	10 <sup>10</sup>	-	-	10 <sup>10</sup>	-	Ω
Capacitance	1MHz	С	-	-	2.0	-	-	2.0	-	-	2.0	рF
Life Ratings												
Surge Life	10kA (PW=15µs)	-	1,300	-	-	1,300	-	-	1,300	-	-	surges

### Specifications (@25°C)

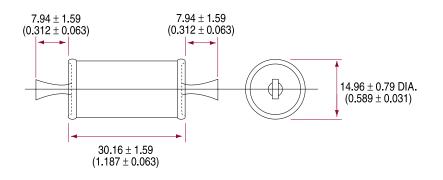
			UBT15.0 UGT15.0			l						
Parameter	Conditions	Symbol	Min	Nom	Max	Min	Nom	Max	Units			
Device Specifications												
DC Breakdown	100V/s	V <sub>BD</sub>	13.5	15.0	16.5	18.0	20.0	22.0	kV			
Impulse Breakdown	5kV/µs	V <sub>bd</sub>	-	-	18.0	-	-	24.0	kV			
Insulation Resistance	100V	IR	-	10 <sup>10</sup>	-	-	10 <sup>10</sup>	-	Ω			
Capacitance	1MHz	С	-	-	2.0	-	-	2.0	рF			
Life Ratings												
Surge Life	10kA (PW=15µs)	-	1,300	-	-	1,300	-	-	surges			

#### MECHANICAL DIMENSIONS mm/(inches)

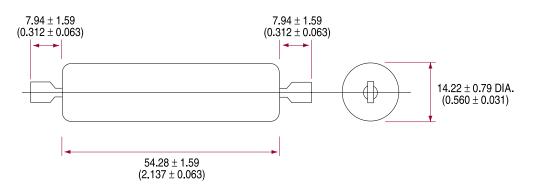
**UBD Series** 



**UBT Series** 







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